

Publications of Dimitrios Tsamakis

Journals

1. Anastassopoulos, A., Kyritsakis, A., Xanthakis, J.P., Sargentis, C., Tsamakis, D. A 3-dimensional Wentzel-Krammers-Brillouin calculation of the charging and retention times of metal nanoparticles in a dielectric matrix (2013) Thin Solid Films 543 PP. 177 - 179
2. Stamataki, M., Tsamakis, D., Xanthakis, J.P., Ali, H.A., Esmaili-Sardari, S., Iliadis, A.A. Electrical characterization of Cr Schottky contacts on undoped and Ni-doped p-ZnO films grown by pulsed laser deposition on Si (1 0 0) substrates (2013) Microelectronic Engineering 104 PP. 95 - 99
3. Stamataki, M., Fasaki, I., Tsonos, G., Tsamakis, D., Kompitsas, M. Annealing effects on the structural, electrical and H₂ sensing properties of transparent ZnO thin films, grown by pulsed laser deposition (2009) Thin Solid Films 518 (4) PP. 1326 - 1331
4. Brilis, N.; Tsamakis, D.; Ali, H.; et al. Electrical conduction effects at low temperatures in undoped ZnO thin films grown by Pulsed Laser Deposition on Si substrates THIN SOLID FILMS Volume: 516 Issue: 12 Pages: 4226-4231 Published: APR 30 (2008)
5. Stamataki, M., Tsamakis, D., Brilis, N., Fasaki, I., Giannoudakos, A., Kompitsas, M. Hydrogen gas sensors based on PLD grown NiO thin film structures (2008) Physica Status Solidi (A) Applications and Materials Science 205 (8) PP. 2064 - 2068
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9. C. Sargentis, K. Giannakopoulos, A. Travlos, D. Tsamakis, Electrical characterization of MOS memory devices containing metallic nanoparticles and a high-k control oxide layer, Surface Science 601, (13), 2859-2863, July 2007
10. C. Pandis, N. Brillis, D. Tsamakis, et al., Role of low O₂ pressure and growth temperature on electrical transport of PLD grown ZnO thin films on Si substrates, Solid-State Electronics 50 (6): 1119-1123, Jun. 2006

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12. N. Brillis, P. Romesis, D. Tsamakis, M. Kompitsas, *Influence of pulsed laser deposition (PLD) parameters on the H₂ sensing properties of zinc oxide thin films*, Superlattices and Microstructures 38 (4-6): 283-290, Oct.-Dec. **2005**
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14. D. Tsamakis, C. Sargentis, A. Kuznetsov, D. Lampakis, *Electrical parameters in highly doped strained n-Si_{1-x}Gex epilayers grown on Si substrates*, Solid-State Electronics 48 (10-11): 2095-2098, Oct.-Nov. **2004**
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